

General Description

The WSD2098 is the highest performance trench N-ch MOSFETs with extreme high cell density , which provide excellent RDSON and gate charge for most of the small power switching and load switch applications.

The WSD2098 meet the RoHS and Green Product requirement with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent Cdv/dt effect decline
- Green Device Available

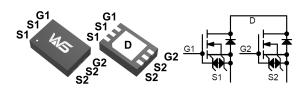
Product Summery

| BV _{DSS} | R _{DSON} | I _D |
|-------------------|-------------------|----------------|
| 20V | 7.0mΩ | 9.7A |

Applications

- Power Management in Notebook Computer, Portable Equipment and Battery Powered Systems.
- DC-DC Power System
- ESD:2KV

DFN2X3A-6_EP Pin Configuration



Absolute Maximum Ratings

| Symbol | Parameter | Rating | Units | |
|--------------------------------------|---|------------|------------|--|
| V_{DS} | Drain-Source Voltage | 20 | V | |
| V_{GS} | Gate-Source Voltage | ±12 | V | |
| I _D @T _A =25℃ | Continuous Drain Current, V _{GS} @ 4.5V ¹ | 9.7 | А | |
| I _D @T _A =70℃ | Continuous Drain Current, V _{GS} @ 4.5V ¹ | 7.5 | А | |
| I _{DM} | Pulsed Drain Current ² | 38 | А | |
| P _D @T _A =25°C | Total Power Dissipation ³ | 1.0 | W | |
| P _D @T _A =70°C | Total Power Dissipation ³ | 0.6 | W | |
| T _{STG} | Storage Temperature Range | -55 to 150 | $^{\circ}$ | |
| TJ | Operating Junction Temperature Range | -55 to 150 | $^{\circ}$ | |

Thermal Data

| Symbol | Parameter | Тур. | Max. | Unit |
|------------------|---|------|------|------|
| R _{θJA} | Thermal Resistance Junction-ambient ¹ (Steady State) | | 127 | °C/W |
| R _{θJA} | Thermal Resistance Junction-ambient ¹ (t<10S) | | 80 | °C/W |



Electrical Characteristics (T_J=25 C, unless otherwise noted)

| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit |
|--------------------------------------|--|---|------|-------|------|------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V , I _D =250uA | 20 | | | V |
| $\triangle BV_{DSS}/\triangle T_{J}$ | BVDSS Temperature Coefficient | Reference to 25℃, I _D =1mA | | 0.022 | | V/°C |
| R _{DS(ON)} | Static Drain-Source On-Resistance ² | V _{GS} =4.5V , I _D =5.5A | | 7.0 | 9.0 | mΩ |
| | | V _{GS} =2.5V , I _D =5.5A | | 10.5 | 13.5 | |
| V _{GS(th)} | Gate Threshold Voltage | V _{GS} =V _{DS} , I _D =250uA | 0.5 | 0.7 | 1.0 | V |
| $\triangle V_{GS(th)}$ | V _{GS(th)} Temperature Coefficient | | | -2.32 | | mV/℃ |
| | Drain-Source Leakage Current | V _{DS} =16V , V _{GS} =0V , T _J =25℃ | | | 1 | |
| I _{DSS} | | V _{DS} =16V , V _{GS} =0V , T _J =55℃ | | | 5 | uA |
| I _{GSS} | Gate-Source Leakage Current | V_{GS} = $\pm12V$, V_{DS} = $0V$ | | | ±100 | nA |
| gfs | Forward Transconductance | V _{DS} =5V , I _D =10A | | 65 | | S |
| R_g | Gate Resistance | V _{DS} =0V , V _{GS} =0V , f=1MHz | | 11 | | Ω |
| Qg | Total Gate Charge (4.5V) | V _{DS} =10V , V _{GS} =4.5V , I _D =5.5A | 10 | 23.2 | 15 | |
| Q _{gs} | Gate-Source Charge | | | 1.9 | | nC |
| Q_{gd} | Gate-Drain Charge | | | 4.8 | | |
| T _{d(on)} | Turn-On Delay Time | | | 8 | | |
| Tr | Rise Time | V_{DD} =10V , V_{GS} =10V , R_{G} =1 Ω , | | 20 | | |
| T _{d(off)} | Turn-Off Delay Time | I _D =1A ,RL=10Ω | | 935 | | ns |
| T _f | Fall Time | | | 410 | | |
| C _{iss} | Input Capacitance | V _{DS} =10V , V _{GS} =0V , f=1MHz | 1000 | 1470 | 1920 | |
| Coss | Output Capacitance | | 150 | 258 | 295 | pF |
| C _{rss} | Reverse Transfer Capacitance | | 100 | 202 | 288 | |

Diode Characteristics

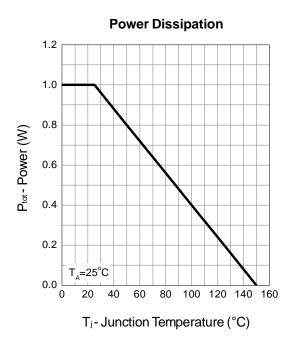
| Symbol | Parameter | Conditions | Min. | Тур. | Max. | Unit |
|-----------------|--|--|------|------|------|------|
| I _S | Continuous Source Current ^{1,4} | V _G =V _D =0V , Force Current | | | 2 | Α |
| I _{SM} | Pulsed Source Current ^{2,4} | | | | 8 | Α |
| V _{SD} | Diode Forward Voltage ² | V _{GS} =0V , I _S =1A , T _J =25℃ | | 0.7 | 1.3 | V |
| t _{rr} | Reverse Recovery Time | lF=5.5A,dI/dt=100A/μs , T _J =25℃ | | 445 | | nS |
| Q _{rr} | Reverse Recovery Charge | | | 2175 | | nC |

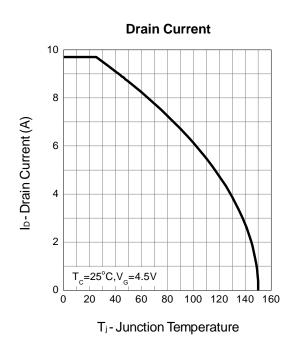
Note:

- 1. The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper, t<10sec.
- 2.The data tested by pulsed , pulse width \leq 300us , duty cycle \leq 2%
- 3.The power dissipation is limited by 150 ℃ junction temperature
- $\textbf{4.The data is theoretically the same as } \textbf{I}_{D} \text{ and } \textbf{I}_{DM} \text{ , in real applications , should be limited by total power dissipation.}$

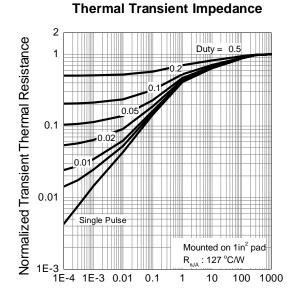


Typical Characteristics





V_{DS} - Drain - Source Voltage (V)

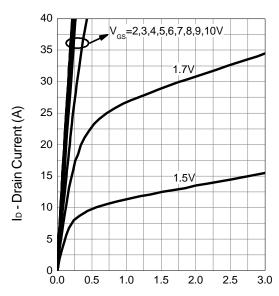


Square Wave Pulse Duration (sec)



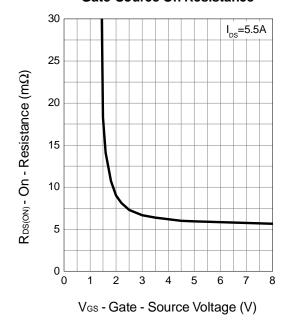
Typical Characteristics

Output Characteristics

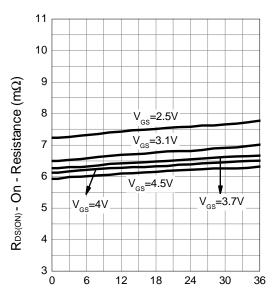


V_{DS} - Drain - Source Voltage (V)

Gate-Source On Resistance

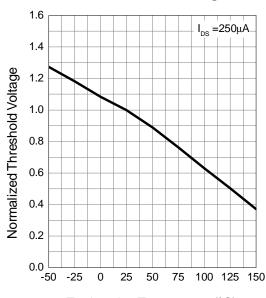


Drain-Source On Resistance



ID-Drain Current (A)

Gate Threshold Voltage

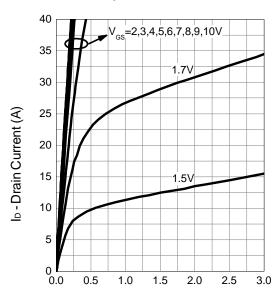


T_j - Junction Temperature (°C)



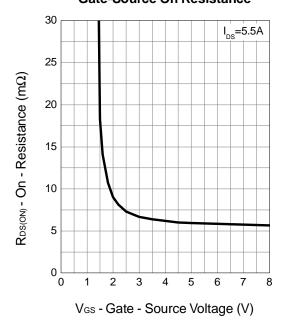
Typical Characteristics

Output Characteristics

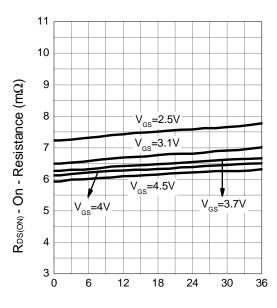


V_{DS} - Drain - Source Voltage (V)

Gate-Source On Resistance

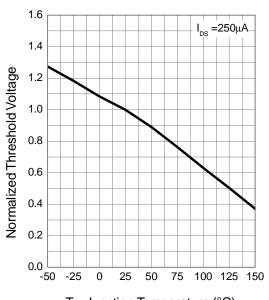


Drain-Source On Resistance



ID-Drain Current (A)

Gate Threshold Voltage



T_j - Junction Temperature (°C)



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